

Amendments to the Specification:

Please add the following new paragraph at page 1, after the title of the application:

This application is the U.S. National Phase application of PCT International Application No. PCT/GB2004/003301, filed July 30, 2004, and claims priority of British Patent Application No. 0317894.4, filed July 31, 2003.

Please add the following heading at page 1, line 4:

FIELD OF THE INVENTION

Please add the following heading at page 1, line 7:

BACKGROUND OF THE INVENTION

Please add the following heading at page 2, line 4:

SUMMARY OF THE INVENTION

Please add the following headings and paragraph at page 2, line 16:

BRIEF DESCRIPTION OF THE DRAWINGS

The invention will now be described by way of example only and with reference to the following drawings in which:

Figure 1 is a schematic diagram of a first example of a hydrogen supply system according to the present invention,

Figure 2 is a schematic diagram of a second example of a hydrogen supply system according to the present invention,

Figure 3 is a schematic diagram of a third example of a hydrogen supply system according to the present invention,

Figure 4 is a schematic diagram of a fourth example of a hydrogen supply system according to the present invention,

Figure 5 is a graph showing hydrogen absorption for the $\text{Ca}_{0.7}\text{Mn}_{0.3}\text{Ni}_5$ material following a 2.3 - 3.5 bars pressure change at 38°C,

Figure 6 is a graph showing hydrogen absorption for the $\text{Ca}_{0.7}\text{Mn}_{0.3}\text{Ni}_5$ material following a 3.5 - 2.7 bars pressure change at 38°C,

Figure 7 is a graph showing absorption isotherms for $\text{LaNi}_{4.7}\text{Al}_{0.3}$ at temperatures ranging from 27 to 50°C,

Figure 8 is a graph showing desorption isotherms for $\text{LaNi}_{4.7}\text{Al}_{0.3}$ at temperatures ranging from 28 to 50°C,

Figure 9 is a graph showing hydrogen absorption for the MgH_2 1 wt% Ni material at 300°C; and

Figure 10 is a graph showing hydrogen desorption for the MgH_2 1 wt% Ni material at 300°C.

DETAILED DESCRIPTION OF THE INVENTION